NSN 5961-01-132-7791

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View Online at https://aerobasegroup.com/nsn/5961-01-132-7791
Inclosure Material:
Metal
Overall Length:
0.450 inches
Function For Which Designed:
Voltage regulator
End Application:
Multi hull 03950
Mounting Facility Quantity:
1
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
Do-5
Electrode Internally-electrically Connected To Case:
Anode
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case and quality assurance level tx
Overall Width Across Flats:
Between 0.667 inches and 0.687 inches
Thread Size:
0.250 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
7.9 regulator voltage
Current Rating Per Characteristic:
6.360 amperes repetitive peak forward current
Power Rating Per Characteristic:
50.0 watts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius ambient air
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Thread Series Designator:
Unf
Terminal Type And Quantity:
1 tab, solder lug and 1 threaded stud
Specification Data:

N/a

Shelf Life:

81349-mil-s-19500/358 government specification

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Demilitarization:

No

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